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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/708,748	03/23/2004	Wei Lu	FIS920030308	2747	
29154	7590 08/23/2005		EXAM	EXAMINER	
FREDERICK W. GIBB, III			JOHNSTON, PHILLIP A		
MCGINN & G	•			D. D	
2568-A RIVA ROAD			ART UNIT	PAPER NUMBER	
SUITE 304			2881		
ANNAPOLIS, MD 21401			DATE MAILED: 08/23/2005		

Please find below and/or attached an Office communication concerning this application or proceeding.

·				TU			
		Application No.	Applicant(s)				
Office Action Summary		10/708,748	LU ET AL.				
		Examiner	Art Unit				
		Phillip A. Johnston	2881				
Period fo	The MAILING DATE of this communication aported in the communication approximation approximation are set of the communication approximation and the communication approximation are set of the communication approximation and the communication are set of the communication are s	opears on the cover sheet wit	h the correspondence address				
THE - External control	MAILING DATE OF THIS COMMUNICATION MAILING DATE OF THIS COMMUNICATION ensions of time may be available under the provisions of 37 CFR 1 or SIX (6) MONTHS from the mailing date of this communication. e period for reply specified above is less than thirty (30) days, a reduce to reply is specified above, the maximum statutory period ure to reply within the set or extended period for reply will, by staturely received by the Office later than three months after the mailined patent term adjustment. See 37 CFR 1.704(b).	.136(a). In no event, however, may a re ply within the statutory minimum of thirty d will apply and will expire SIX (6) MON <sup>1</sup> tte, cause the application to become AB	ply be timely filed  (30) days will be considered timely.  (HS from the mailing date of this communication.  ANDONED (35 U.S.C. § 133).				
Status							
1)⊠	Responsive to communication(s) filed on 13	September 2004.					
2a)□	This action is <b>FINAL</b> . 2b)⊠ Th	is action is non-final.					
3)[	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
	closed in accordance with the practice under	Ex parte Quayle, 1935 C.D.	11, 453 O.G. 213.				
Disposit	ion of Claims						
4)⊠	☑ Claim(s) <u>1-20</u> is/are pending in the application.						
	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)□	Claim(s) is/are allowed.						
	☑ Claim(s) <u>1-20</u> is/are rejected.						
	Claim(s) is/are objected to.						
8)[_	Claim(s) are subject to restriction and	or election requirement.					
Applicat	ion Papers						
9)[	The specification is objected to by the Examir	ner.					
10)⊠	☑ The drawing(s) filed on <u>23 <i>March</i> 2004</u> is/are: a)☑ accepted or b)☐ objected to by the Examiner.						
	Applicant may not request that any objection to th	e drawing(s) be held in abeyan	ce. See 37 CFR 1.85(a).				
	Replacement drawing sheet(s) including the corre	•	, ,				
11)	The oath or declaration is objected to by the E	Examiner. Note the attached	Office Action or form PTO-152.				
Priority	under 35 U.S.C. § 119						
•	Acknowledgment is made of a claim for foreig  All b) Some * c) None of:  1. Certified copies of the priority documer  2. Certified copies of the priority documer  3. Copies of the certified copies of the pri application from the International Bure	nts have been received. nts have been received in A iority documents have been	oplication No				
* ;	See the attached detailed Office action for a lis	. , , , ,	eceived.				
Attachmer	• •	ΛΠ <u></u>	turmoni /DTO 4423				
2)  Notice 3)  Infor	ce of References Cited (PTO-892) ce of Draftsperson's Patent Drawing Review (PTO-948) rmation Disclosure Statement(s) (PTO-1449 or PTO/SB/08 er No(s)/Mail Date <u>3-23-2004</u> .	Paper No(s	ummary (PTO-413) )/Mail Date formal Patent Application (PTO-152) 				

Art Unit: 2881

## Detailed Action

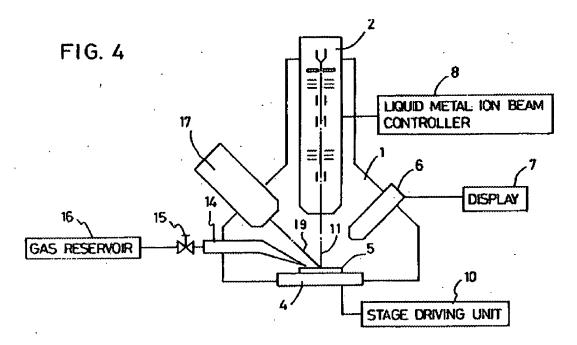
## Claims Rejection - 35 U.S. C. 102

- 1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:
  - (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
  - 2. Claims 1-5,8-12, and 15-18 are rejected under 35 U.S.C. 102 (b) as being clearly anticipated by Fujii, U. S. Patent No. 5,574,280.

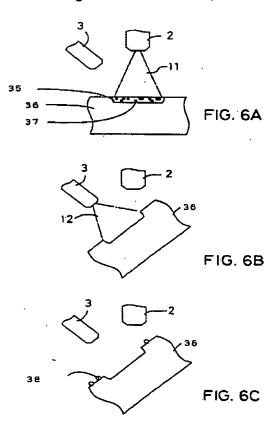
Fujii (280) discloses the following;

(a) Use of electron beam irradiation unit 17 to irradiate hexacarbonyl tungsten gas (organic metal gas) blown by the organic gas source 14 onto the surface of semiconductor device 5, and while irradiated with the energy beam source 17 a tungsten film is formed on the surface. A portion of the sample 5 at the predetermined area is removed (forms a groove) by ion beam sputtering, exposing the cross-section (e.g. wiring at the boundary) of the semiconductor. Subsequent irradiation at the section with the focused ion beam generates secondary particles, which are detected by a detector 6, and then the image of the section is displayed on the display 7 (inspecting the exposed area), as recited in claims 1,8, and 15. See Column 2, line 40-49; Column 4, line 34-45; Column 5, line 47-57; and Figure 4 below;

Art Unit: 2881



(b) The use of a tilted stage shown in Figures 6A-6C; as recited in claims 2,3, and 10. See Figures 6A-6C below;



Application/Control Number: 10/708,748 Page 4

Art Unit: 2881

It is implied herein that, secondary electrons are generated when electron beam source 17 irradiates semiconductor sample 5, and these generated secondary electrons, along with the primary beam electrons, contribute to the dissociation (breakdown) of the organic gas, which results in deposition of the metal coating onto the semiconductor surface, as recited in claims 4,11, and 15.

It is also implied herein that, secondary electrons always have less energy than the primary electrons that generate them, as recited in claims 5 and 12.

## Claims Rejection - 35 U.S.C. 103

3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which the subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

4. Claims 7,14, and 20 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,574,280 to Fujii, in view of Berger, U.S. Patent Pub. No. 20040065826.

Fujii (280) as described above discloses nearly all the limitations of claims 7,14, and 20 but fails to teach the use of an incident electron beam angle between 20 and 70 degrees relative to the sample surface. However Berger (826) discloses a particle-beam system 10 for obtaining an image of a cross-section of a workpiece 11, as

Art Unit: 2881

shown in FIG. 1, includes a shaped-beam ion-projection column 12 configured to project an image of an aperture onto the front surface 14 of the workpiece 11, and further includes a focused-particle-beam imaging column 20, which is an electron beam provided by a scanning electron microscope. The column 20 is oriented along a second axis 22 that is canted relative to the first axis 18 so that it intersects the first axis 18 at a selected angle. The selected angle is preferably between thirty and sixty degrees, as recited in claims 7,14, and 20. See paragraph's [0024], [0025]; [0039]; and Figure 1 below;

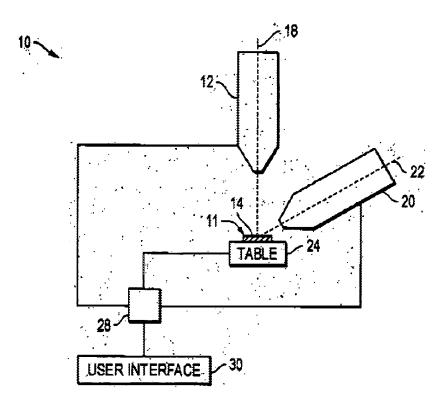


FIG. 1

Therefore it would have been obvious to one of ordinary skill in the art that the ion beam apparatus and method of Fujii (280) can be modified to use the incident electron beam angles specified in the apparatus and method of Berger (826), to provide a method and system for imaging a cross-section of a substrate that is capable of switching from a cutting mode to an imaging mode in order to view the vertical wall of the excavated cross-section.

5. Claims 6,13, and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 5,574,280 to Fujii, in view of Christy, U.S. Patent No. 3,119,707.

Fujii (280) as described above discloses nearly all the limitations of claims 6,13, and 19, but fails to teach the use of electron beams having energy levels between 100 and 10,000 electron volts to form a metal film. However, Christy (707) discloses a method for deposition of thin films that includes the use of a substrate located within an evacuated chamber, that is enveloped with the vapor molecules of a metal-organic compound, which is irradiated with a beam of electrons accelerated at 225 volts, whereby a metal film is formed as the vapor molecules adsorbed on the substrate are decomposed by the electron beam, as recited in claims 6,13, and 19. See Column 2, line 24-32; and Column 4, line 27-40.

Therefore it would have been obvious to one of ordinary skill in the art that the ion beam apparatus and method of Fujii (280) can be modified with the accelerating potentials in the apparatus and method of Christy (707), to provide a beam of

Application/Control Number: 10/708,748

Art Unit: 2881

electrons directed against a vapor of metal organic molecules to form a metal film on a

Page 7

substrate.

Conclusion

6. Any inquiry concerning this communication or earlier communications should be

directed to Phillip Johnston whose telephone number is (571) 272-2475. The examiner

can normally be reached on Monday-Friday from 7:30 am to 4:00 pm. If attempts to

reach the examiner by telephone are unsuccessful, the examiners supervisor John Lee

can be reached at (571) 272-2477. The fax phone number for the organization where

the application or proceeding is assigned is 703 872 9306.

Information regarding the status of an application may be obtained from the

Patent Application Information Retrieval (PAIR) system. Status information for

published applications may be obtained from either Private PAIR or Public PAIR.

Status information for unpublished applications is available through Private PAIR only.

For more information about the PAIR system, see http://pair-direct.uspto.gov. Should

you have questions on access to the Private PAIR system, contact the Electronic

Business Center (EBC) at 866-217-9197 (toll-free).

PJ

August 20, 2005

JOHN R. LEE

SUPERVISORY PATENT EXAMINER

TECHNOLOGY CENTER 2000